

### Product Summary

| $V_{(BR)DSS}$ | $R_{DS(on)MAX}$ | $I_D$ |
|---------------|-----------------|-------|
| 100V          | 17mΩ@10V        | 40A   |
|               | 18mΩ@4.5V       |       |

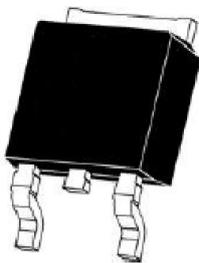
### Feature

- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high  $E_{AS}$
- Excellent package for good heat dissipation

### Application

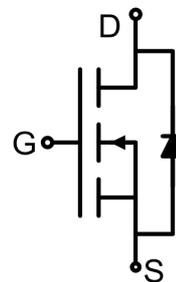
- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

### Package

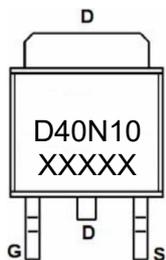


TO-252AB

### Circuit diagram



### Marking



### Absolute maximum ratings (Ta=25°C unless otherwise noted)

| Parameter                            | Symbol          | Value      | Unit          |
|--------------------------------------|-----------------|------------|---------------|
| Drain-Source Voltage                 | $V_{DS}$        | 100        | V             |
| Gate-Source Voltage                  | $V_{GS}$        | $\pm 20$   | V             |
| Continuous Drain Current             | $I_D$           | 40         | A             |
| Pulsed Drain Current                 | $I_{DM}$        | 160        | A             |
| Power Dissipation                    | $P_D$           | 140        | W             |
| Thermal Resistance, Junction-to-Case | $R_{\theta JC}$ | 1.07       | $^{\circ}C/W$ |
| Single pulse avalanche energy        | $E_{AS}$        | 400        | mJ            |
| Junction Temperature                 | $T_J$           | 150        | $^{\circ}C$   |
| Storage Temperature                  | $T_{STG}$       | -55 ~ +150 | $^{\circ}C$   |

### Electrical characteristics (T<sub>A</sub>=25 °C, unless otherwise noted)

| Parameter                                   | Symbol        | Test Condition  | Min. | Typ. | Max.      | Unit       |
|---|---------------|---|------|------|-----------|------------|
| <b>Static Characteristics</b>               |               |   |      |      |           |            |
| Drain-source breakdown voltage              | $V_{(BR)DSS}$ | $V_{GS} = 0V, I_D = 250\mu A$   | 100  |      |           | V          |
| Zero gate voltage drain current             | $I_{DSS}$     | $V_{DS} = 100V, V_{GS} = 0V$  |      |      | 1         | $\mu A$    |
| Gate-body leakage current                   | $I_{GSS}$     | $V_{GS} = \pm 20V, V_{DS} = 0V$   |      |      | $\pm 100$ | nA         |
| Gate threshold voltage                      | $V_{GS(th)}$  | $V_{DS} = V_{GS}, I_D = 250\mu A$   | 0.9  |      | 1.5       | V          |
| Drain-source on-resistance <sup>1)</sup>    | $R_{DS(on)}$  | $V_{GS} = 10V, I_D = 20A$   |      | 12   | 17        | m $\Omega$ |
|   |               | $V_{GS} = 4.5V, I_D = 20A$  |      | 13   | 18        |            |
| Forward transconductance <sup>1)</sup>      | $g_{FS}$      | $V_{DS} = 5V, I_D = 20A$  | 32   |      |           | S          |
| <b>Dynamic characteristics<sup>2)</sup></b> |               |   |      |      |           |            |
| Input Capacitance                           | $C_{iss}$     | $V_{DS} = 30V, V_{GS} = 0V, f = 1MHz$   |      | 3400 |           | pF         |
| Output Capacitance                          | $C_{oss}$     |   |      | 290  |           |            |
| Reverse Transfer Capacitance                | $C_{rss}$     |   |      | 221  |           |            |
| Total Gate Charge                           | $Q_g$         | $V_{DS} = 50V, V_{GS} = 10V, I_D = 20A$   |      | 94   |           | nC         |
| Gate-Source Charge                          | $Q_{gs}$      |   |      | 16   |           |            |
| Gate-Drain Charge                           | $Q_{gd}$      |   |      | 24   |           |            |
| Turn-on delay time                          | $t_{d(on)}$   | $V_{DD} = 30V, V_{GS} = 10V, I_D = 2A$<br>$R_L = 15\Omega, R_{GEN} = 2.5\Omega$ |      | 15   |           | nS         |
| Turn-on rise time                           | $t_r$         |   |      | 11   |           |            |
| Turn-off delay time                         | $t_{d(off)}$  |   |      | 52   |           |            |
| Turn-off fall time                          | $t_f$         |   |      | 13   |           |            |
| <b>Source-Drain Diode characteristics</b>   |               |   |      |      |           |            |
| Diode Forward Current <sup>1)</sup>         | $I_S$         |   |      |      | 40        | A          |
| Diode Forward voltage                       | $V_{DS}$      | $V_{GS} = 0V, I_S = 20A$  |      |      | 1.2       | V          |
| Reverse Recovery Time                       | $t_{rr}$      | $T_J = 25^{\circ}C, I_F = 20A$<br>$di/dt = 100A/\mu s$ <sup>1)</sup>            |      | 33   |           | nS         |
| Reverse Recovery Charge                     | $Q_{rr}$      |   |      | 54   |           | nC         |

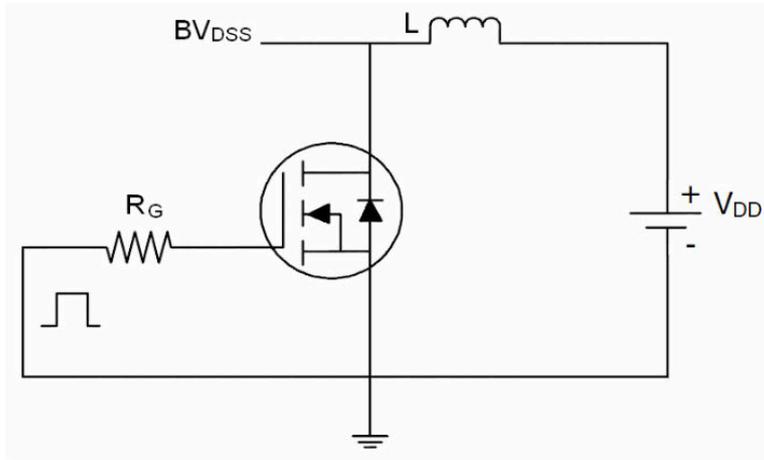
Notes:

1) Pulse Test: Pulse Width < 300 $\mu s$ , Duty Cycle  $\leq 2\%$ .

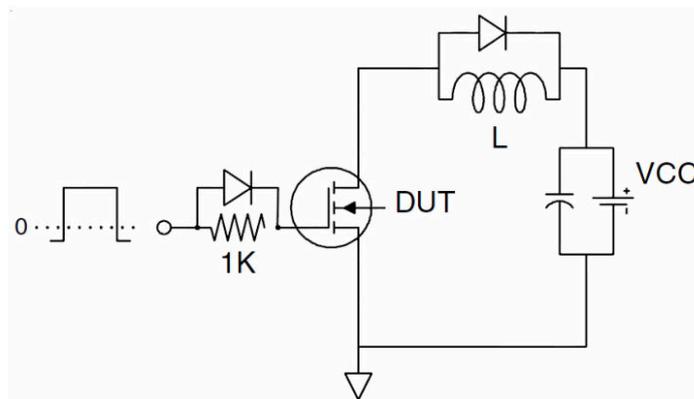
2) Guaranteed by design, not subject to production testing.

## Test Circuit

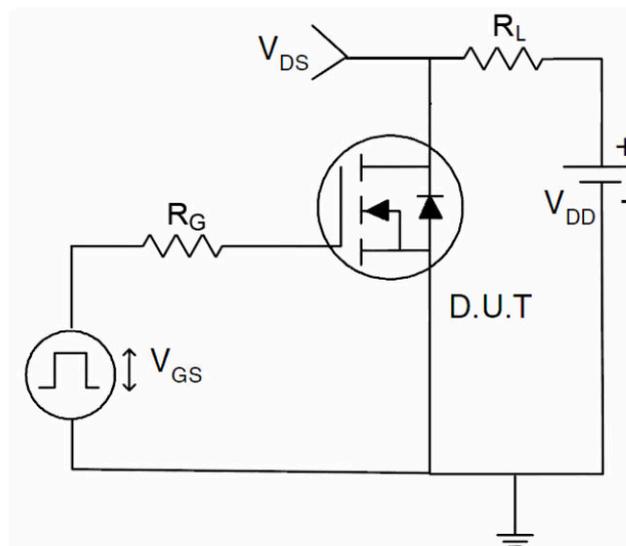
### 1) $E_{AS}$ test Circuit



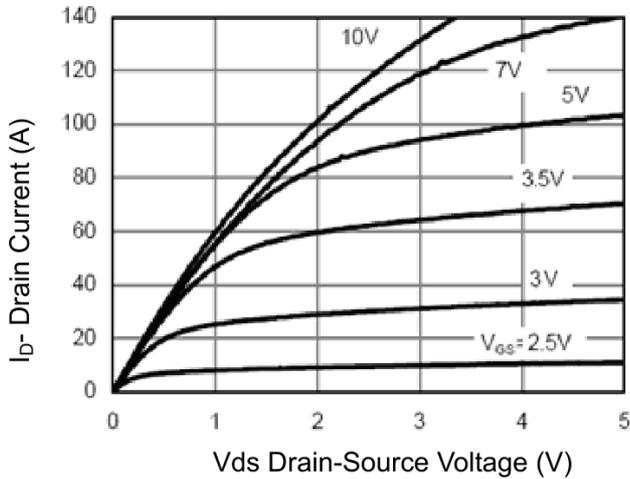
### 2) Gate charge test Circuit



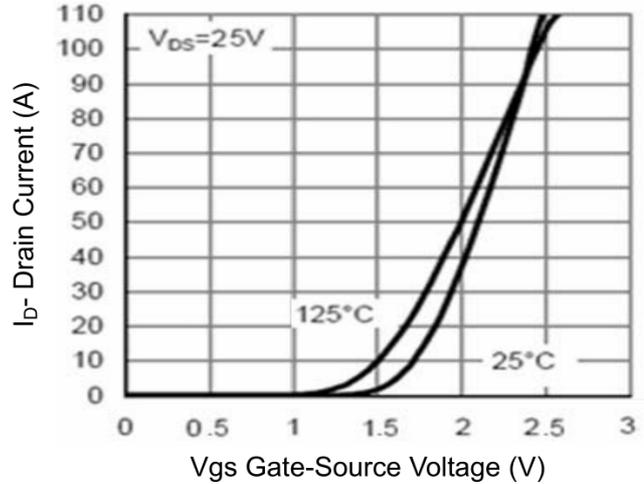
### 3) Switch Time Test Circuit



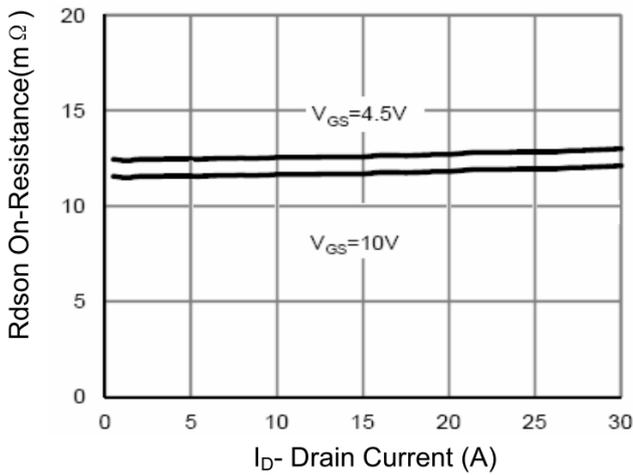
## Typical Characteristics



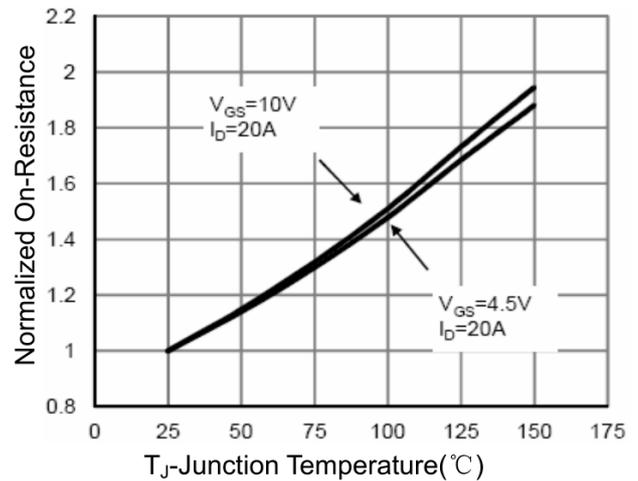
**Figure 1 Output Characteristics**



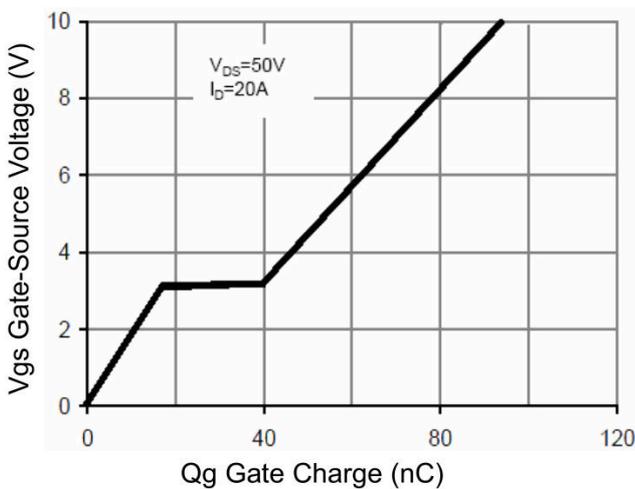
**Figure 2 Transfer Characteristics**



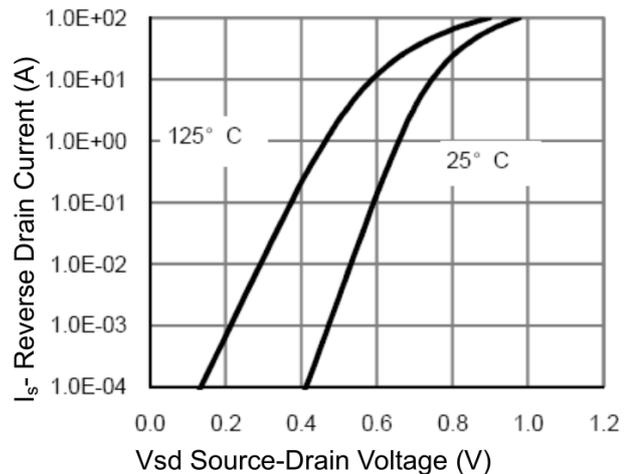
**Figure 3 Rdson- Drain Current**



**Figure 4 Rdson-Junction Temperature**

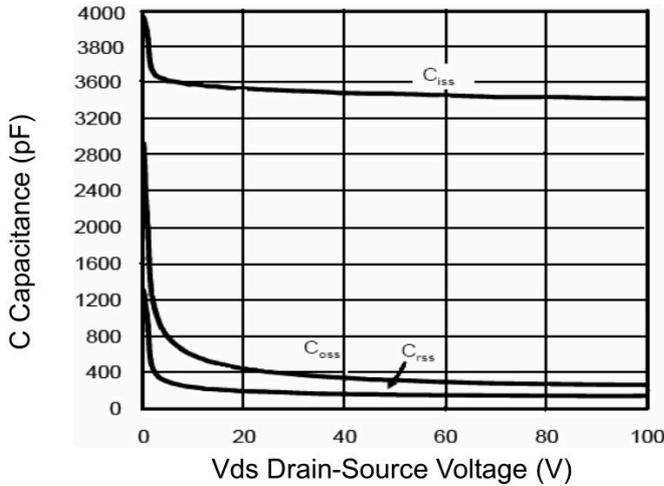


**Figure 5 Gate Charge**

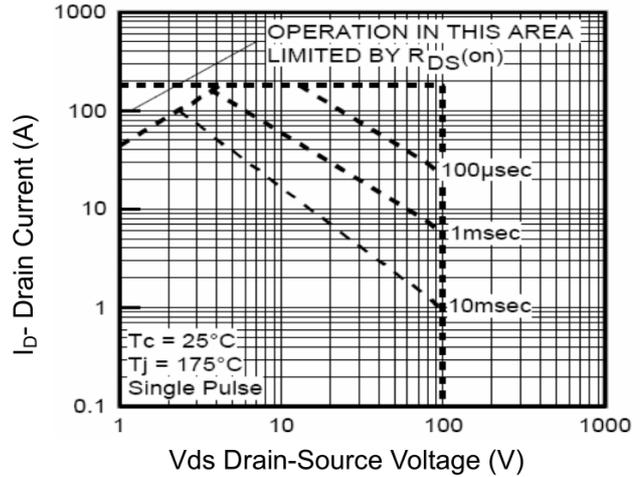


**Figure 6 Source- Drain Diode Forward**

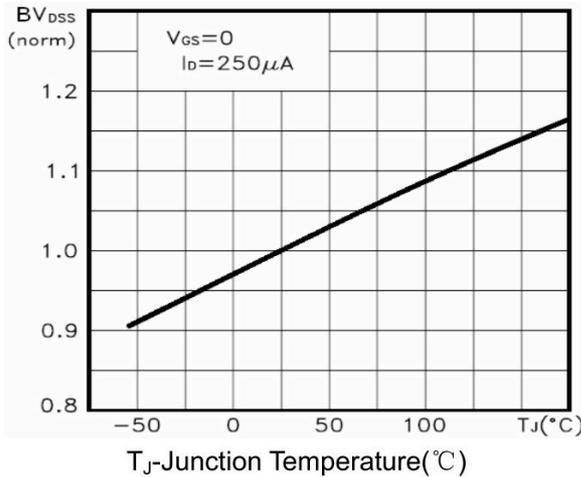
## Typical Characteristics



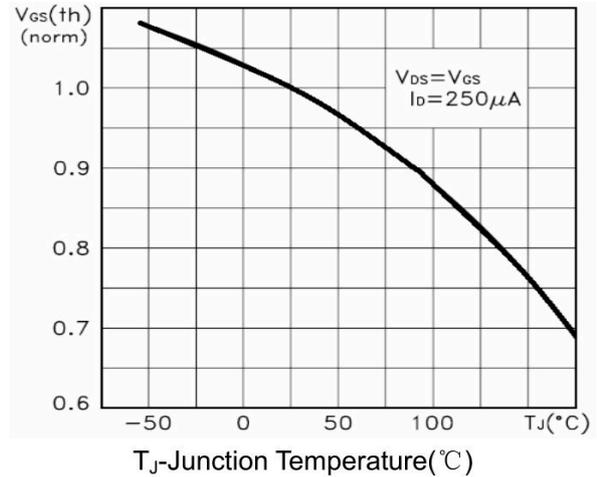
**Figure 7 Capacitance vs Vds**



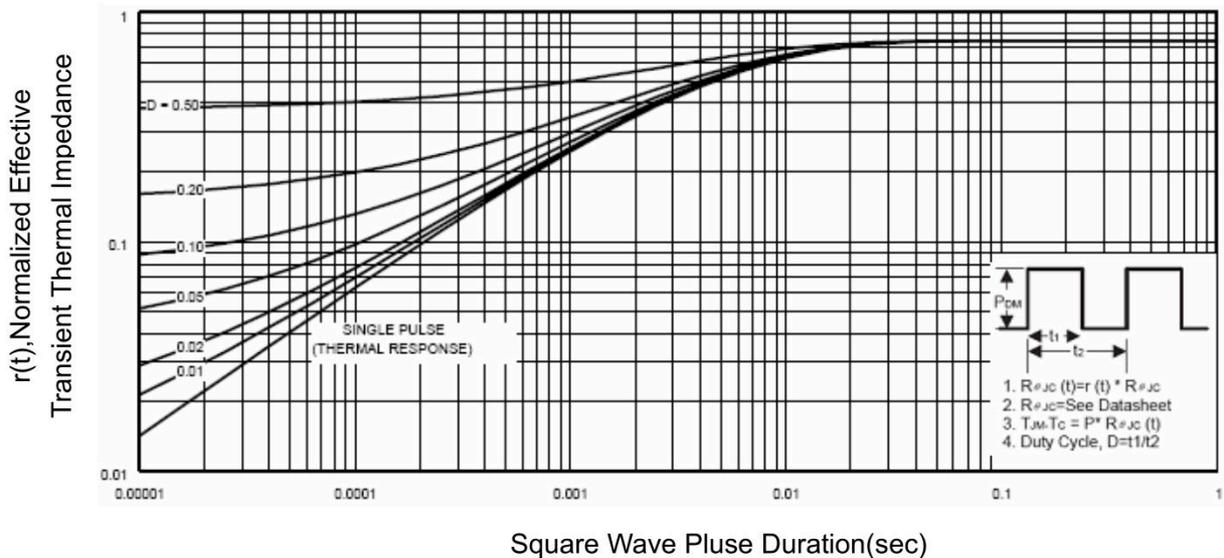
**Figure 8 Safe Operation Area**



**Figure 9 BV<sub>DSS</sub> vs Junction Temperature**

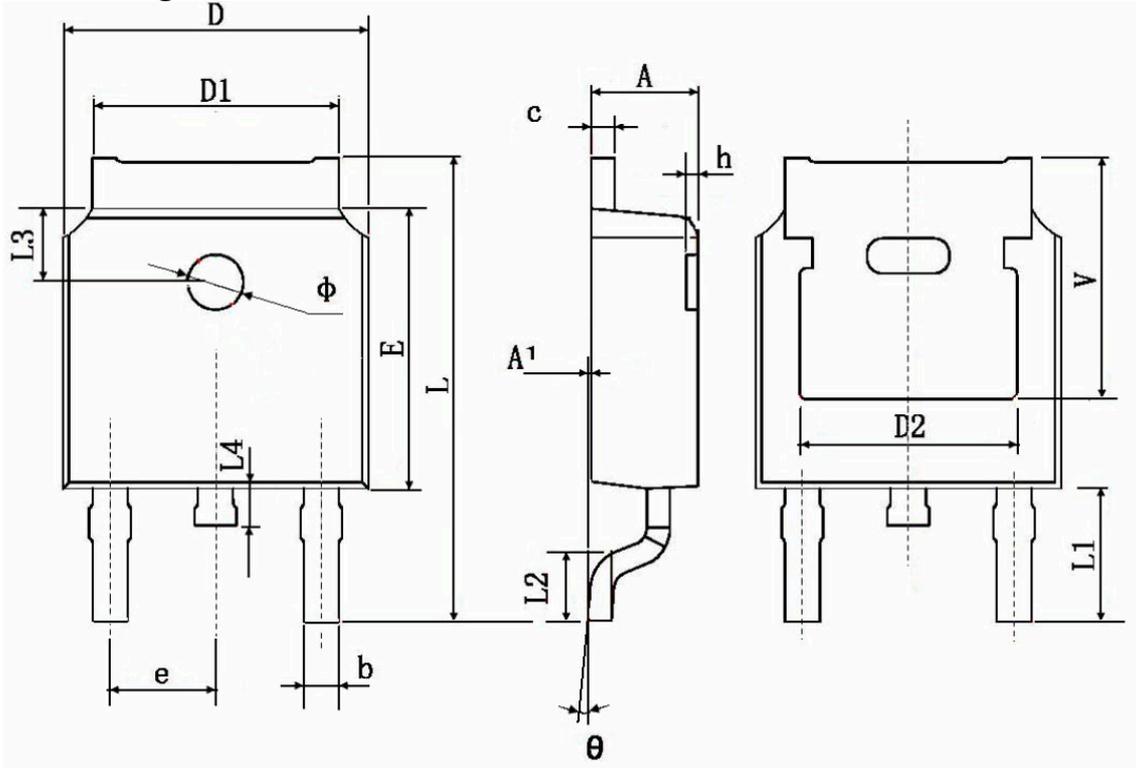


**Figure 10 V<sub>GS(th)</sub> vs Junction Temperature**



**Figure 11 Normalized Maximum Transient Thermal Impedance**

### TO-252AB Package Information



| Symbol | Dimensions In Millimeters |        | Dimensions In Inches |       |
|--------|---------------------------|--------|----------------------|-------|
|        | Min.                      | Max.   | Min.                 | Max.  |
| A      | 2.200                     | 2.400  | 0.087                | 0.094 |
| A1     | 0.000                     | 0.127  | 0.000                | 0.005 |
| b      | 0.660                     | 0.860  | 0.026                | 0.034 |
| c      | 0.460                     | 0.580  | 0.018                | 0.023 |
| D      | 6.500                     | 6.700  | 0.256                | 0.264 |
| D1     | 5.100                     | 5.460  | 0.201                | 0.215 |
| D2     | 4.830 TYP.                |        | 0.190 TYP.           |       |
| E      | 6.000                     | 6.200  | 0.236                | 0.244 |
| e      | 2.186                     | 2.386  | 0.086                | 0.094 |
| L      | 9.800                     | 10.400 | 0.386                | 0.409 |
| L1     | 2.900 TYP.                |        | 0.114 TYP.           |       |
| L2     | 1.400                     | 1.700  | 0.055                | 0.067 |
| L3     | 1.600 TYP.                |        | 0.063 TYP.           |       |
| L4     | 0.600                     | 1.000  | 0.024                | 0.039 |
| Φ      | 1.100                     | 1.300  | 0.043                | 0.051 |
| θ      | 0°                        | 8°     | 0°                   | 8°    |
| h      | 0.000                     | 0.300  | 0.000                | 0.012 |
| V      | 5.350 TYP.                |        | 0.211 TYP.           |       |